

# General Purpose Transistors

**PNP Silicon** 

# **BC856ALT1G Series**

#### **Features**

- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

## MAXIMUM RATINGS (T<sub>A</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Emitter Voltage BC856, SBC856 BC857, SBC857 BC858, NSVBC858, BC859	V <sub>CEO</sub>	-65 -45 -30	>
Collector-Base Voltage BC856, SBC856 BC857, SBC857 BC858, NSVBC858, BC859	V <sub>CBO</sub>	-80 -50 -30	V
Emitter-Base Voltage	V <sub>EBO</sub>	-5.0	V
Collector Current - Continuous	I <sub>C</sub>	-100	mAdc
Collector Current - Peak	I <sub>C</sub>	-200	mAdc

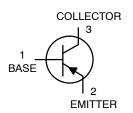
#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, (Note 1) T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1

- 1.  $FR-5 = 1.0 \times 0.75 \times 0.062$  in.
- 2. Alumina =  $0.4 \times 0.3 \times 0.024$  in 99.5% alumina.





SOT-23 (TO-236) CASE 318 STYLE 6

#### **MARKING DIAGRAM**



xx = Device Code

xx = (Refer to page 6)

M = Date Code\*

= Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation and/or overbar may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

# **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage BC856, SBC856 Series (I <sub>C</sub> = -10 mA) BC857, SBC857 Series	V <sub>(BR)CEO</sub>	-65 -45	_ _	- -	V
BC858, NSBVC858 BC859 Series		-30	-	-	
Collector – Emitter Breakdown Voltage BC856 S, SBC856eries (I <sub>C</sub> = -10 μA, V <sub>FB</sub> = 0) BC857A, SBC857A, BC857B, SBC857B Only	$V_{(BR)CES}$	-80 -50	-	-	V
$(I_C = -10 \mu A, V_{EB} = 0)$ BC857A, SBC857A, BC857B, SBC857B Only BC858, NSVB858, BC859 Series		-30 -30	_	_	
Collector – Base Breakdown Voltage BC856, SBC856 Series	V <sub>(BR)CBO</sub>	-80	-	-	V
$(I_C = -10 \mu A)$ BC857, SBC857 Series BC858, NSVBC858, BC859 Series		-50 -30	_	_	
Emitter – Base Breakdown Voltage BC856, SBC856 Series	V <sub>(BR)EBO</sub>	-5.0	-	-	V
(I <sub>E</sub> = -1.0 μA) BC857, SBC857 Series BC858, NSVBC858, BC859 Series		-5.0 -5.0	_	_ _	
Collector Cutoff Current ( $V_{CB} = -30 \text{ V}$ ) ( $V_{CB} = -30 \text{ V}$ , $T_A = 150^{\circ}\text{C}$ )	I <sub>CBO</sub>	- -	_ _	-15 -4.0	nA μA
ON CHARACTERISTICS					
DC Current Gain BC856A, SBC856A, BC857A, SBC857A, BC858A $(I_C = -10 \mu A, V_{CE} = -5.0 \text{ V})$ BC856B, SBC856B, BC857B, SBC857B,	h <sub>FE</sub>	-	90 150	-	_
BC858B, NSVBC858B BC857C, SBC857C BC858C		_	270	_	
(I <sub>C</sub> = -2.0 mA, V <sub>CE</sub> = -5.0 V) BC856A, SBC856A, BC857A,		125	180	250	
SBC857A, BC858A BC856B, SBC856B, BC857B, SBC857B, BC858B,		220	290	475	
NSVBC858B, BC859B BC857C, SBC857C, BC858C, BC859C		420	520	800	
Collector - Emitter Saturation Voltage	V <sub>CE(sat)</sub>				V
$(I_C = -10 \text{ mA}, I_B = -0.5 \text{ mA})$ $(I_C = -100 \text{ mA}, I_B = -5.0 \text{ mA})$		_	_	-0.3 -0.65	
Base - Emitter Saturation Voltage	V <sub>BE(sat)</sub>				V
$(I_C = -10 \text{ mA}, I_B = -0.5 \text{ mA})$ $(I_C = -100 \text{ mA}, I_B = -5.0 \text{ mA})$		-	-0.7 -0.9	-	
Base – Emitter On Voltage	V <sub>BE(on)</sub>				V
$(I_C = -2.0 \text{ mA}, V_{CE} = -5.0 \text{ V})$ $(I_C = -10 \text{ mA}, V_{CE} = -5.0 \text{ V})$		-0.6 -	_	-0.75 -0.82	
SMALL-SIGNAL CHARACTERISTICS					
Current – Gain – Bandwidth Product (I <sub>C</sub> = –10 mA, V <sub>CE</sub> = –5.0 Vdc, f = 100 MHz)	f <sub>T</sub>	100	_	-	MHz
Output Capacitance (V <sub>CB</sub> = -10 V, f = 1.0 MHz)	C <sub>ob</sub>	-	-	4.5	pF
Noise Figure	NF				dB
$(I_C = -0.2 \text{ mA}, V_{CE} = -5.0 \text{ Vdc}, R_S = 2.0 \text{ k}Ω, f = 1.0 \text{ kHz}, BW = 200 \text{ Hz})$ BC856, SBC856, BC857, SBC857, BC858, NSVBC858 Series BC859 Series		- -	_ _	10 4.0	
SWITCHING CHARACTERISTICS			<u> </u>	<u> </u>	ı
Delay Time ( $V_{CC} = -3.0 \text{ Vdc}$ , $I_C = -10 \text{ mA}$ , $I_E = -1 \text{ mA}$ )	t <sub>d</sub>	-	35	-	ns
Rise Time ( $V_{CC} = -3.0 \text{ Vdc}$ , $I_C = -10 \text{ mA}$ , $I_E = -1 \text{ mA}$ )	t <sub>r</sub>	-	25	-	ns
Storage Time ( $V_{CC} = -3.0 \text{ Vdc}$ , $I_C = -10 \text{ mA}$ , $I_E = -1 \text{ mA}$ )	t <sub>s</sub>	-	310	-	ns
Fall Time ( $V_{CC} = -3.0 \text{ Vdc}$ , $I_C = -10 \text{ mA}$ , $I_E = -1 \text{ mA}$ )	t <sub>f</sub>	-	40	-	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

## BC857/BC858/BC859/SBC857/NSVBC858

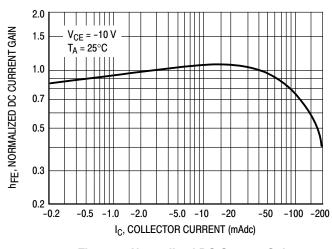


Figure 1. Normalized DC Current Gain

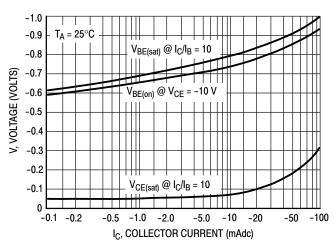


Figure 2. "Saturation" and "On" Voltages

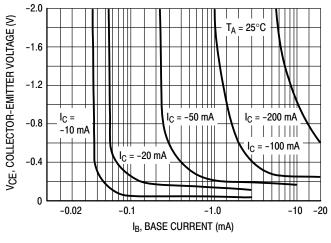


Figure 3. Collector Saturation Region

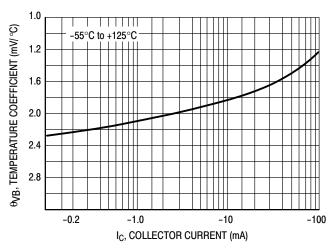


Figure 4. Base-Emitter Temperature Coefficient

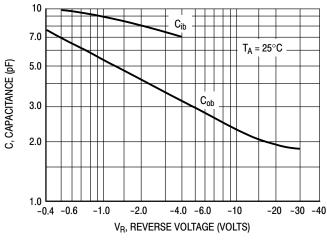


Figure 5. Capacitances

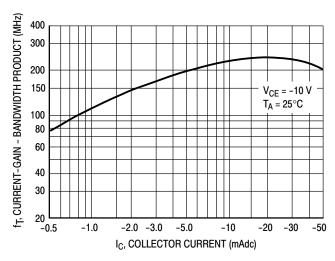


Figure 6. Current-Gain - Bandwidth Product

## BC856/SBC856

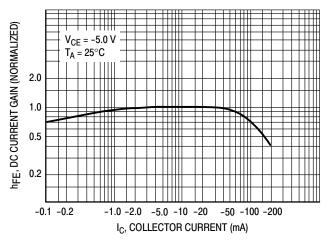


Figure 7. DC Current Gain

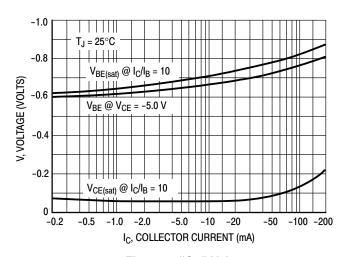


Figure 8. "On" Voltage

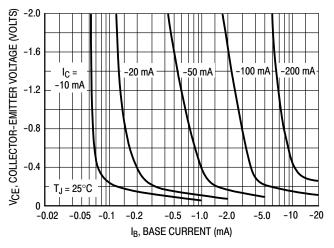


Figure 9. Collector Saturation Region

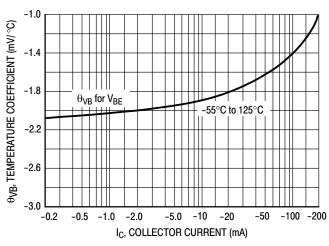


Figure 10. Base-Emitter Temperature Coefficient

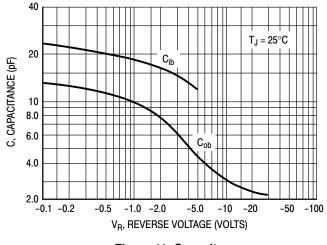


Figure 11. Capacitance

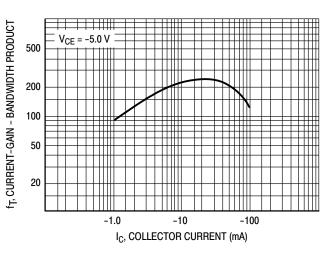


Figure 12. Current-Gain - Bandwidth Product

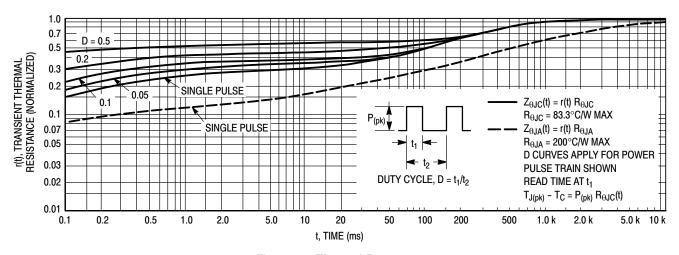


Figure 13. Thermal Response

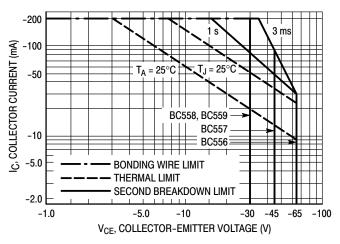


Figure 14. Active Region Safe Operating Area

The safe operating area curves indicate  $I_C$ – $V_{CE}$  limits of the transistor that must be observed for reliable operation. Collector load lines for specific circuits must fall below the limits indicated by the applicable curve.

The data of Figure 14 is based upon  $T_{J(pk)} = 150^{\circ}C$ ;  $T_C$  or  $T_A$  is variable depending upon conditions. Pulse curves are valid for duty cycles to 10% provided  $T_{J(pk)} \le 150^{\circ}C$ .  $T_{J(pk)}$  may be calculated from the data in Figure 13. At high case or ambient temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by the secondary breakdown.

#### **ORDERING INFORMATION**

Device	Marking	Package	Shipping <sup>†</sup>	
BC856ALT1G	3A	SOT-23	3,000 / Tape & Reel	
SBC856ALT1G*		(Pb-Free)		
BC856ALT3G			10,000 / Tape & Reel	
BC856BLT1G	3B	SOT-23	3,000 / Tape & Reel	
SBC856BLT1G*		(Pb-Free)		
BC856BLT3G			10,000 / Tape & Reel	
SBC856BLT3G*				
BC857ALT1G	3E	SOT-23	3,000 / Tape & Reel	
SBC857ALT1G*		(Pb-Free)		
BC857BLT1G	3F	SOT-23	3,000 / Tape & Reel	
SBC857BLT1G*		(Pb-Free)		
BC857BLT3G			10,000 / Tape & Reel	
NSVBC857BLT3G*				
BC857CLT1G	3G	SOT-23 (Pb-Free)	3,000 / Tape & Reel	
SBC857CLT1G*				
BC857CLT3G			10,000 / Tape & Reel	
BC858ALT1G	3J	SOT-23 (Pb-Free)	3,000 / Tape & Reel	
BC858BLT1G	3K	SOT-23		
NSVBC858BLT1G*		(Pb-Free)		
BC858BLT3G		SOT-23 (Pb-Free)	10,000 / Tape & Reel	
BC858CLT1G	3L	SOT-23 (Pb-Free)	3,000 / Tape & Reel	
BC858CLT3G		SOT-23 (Pb-Free)	10,000 / Tape & Reel	
BC859BLT1G	4B	SOT-23 (Pb-Free)	3,000 / Tape & Reel	
BC859BLT3G		SOT-23 (Pb-Free)	10,000 / Tape & Reel	
BC859CLT1G	4C	SOT-23 (Pb-Free)	3,000 / Tape & Reel	
BC859CLT3G		SOT-23 (Pb-Free)	10,000 / Tape & Reel	

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

<sup>\*</sup>S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

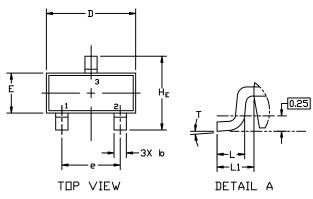




**SOT-23 (TO-236)** CASE 318 ISSUE AT

**DATE 01 MAR 2023** 









#### NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M,1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	MILLIMETERS		INCHES			
DIM	MIN.	N□M.	MAX.	MIN.	N□M.	MAX.
Α	0.89	1.00	1.11	0.035	0.039	0.044
A1	0.01	0.06	0.10	0.000	0.002	0.004
b	0.37	0.44	0.50	0.015	0.017	0.020
С	0.08	0.14	0.20	0.003	0.006	0.008
D	2.80	2.90	3.04	0.110	0.114	0.120
Ε	1.20	1.30	1.40	0.047	0.051	0.055
e	1.78	1.90	2.04	0.070	0.075	0.080
L	0.30	0.43	0.55	0.012	0.017	0.022
L1	0.35	0.54	0.69	0.014	0.021	0.027
HE	2.10	2.40	2.64	0.083	0.094	0.104
Т	0*		10°	0*		10°

# GENERIC MARKING DIAGRAM\*



XXX = Specific Device Code

M = Date Code

■ = Pb-Free Package



RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

## **STYLES ON PAGE 2**

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<sup>\*</sup>This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

# MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



## **SOT-23 (TO-236)** CASE 318 ISSUE AT

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STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR	STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE	1	
STYLE 9: PIN 1. ANODE 2. ANODE 3. CATHODE	STYLE 10: PIN 1. DRAIN 2. SOURCE 3. GATE	STYLE 11: PIN 1. ANODE 2. CATHODE 3. CATHODE-ANODE	STYLE 12: PIN 1. CATHODE 2. CATHODE 3. ANODE	STYLE 13: PIN 1. SOURCE 2. DRAIN 3. GATE	STYLE 14: PIN 1. CATHODE 2. GATE 3. ANODE
STYLE 15: PIN 1. GATE 2. CATHODE 3. ANODE	STYLE 16: PIN 1. ANODE 2. CATHODE 3. CATHODE	STYLE 17: PIN 1. NO CONNECTION 2. ANODE 3. CATHODE	STYLE 18: PIN 1. NO CONNECTION 2. CATHODE 3. ANODE	STYLE 19: I PIN 1. CATHODE 2. ANODE 3. CATHODE-ANODE	STYLE 20: PIN 1. CATHODE 2. ANODE 3. GATE
STYLE 21: PIN 1. GATE 2. SOURCE 3. DRAIN	STYLE 22: PIN 1. RETURN 2. OUTPUT 3. INPUT	STYLE 23: PIN 1. ANODE 2. ANODE 3. CATHODE	STYLE 24: PIN 1. GATE 2. DRAIN 3. SOURCE	STYLE 25: PIN 1. ANODE 2. CATHODE 3. GATE	STYLE 26: PIN 1. CATHODE 2. ANODE 3. NO CONNECTION
STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE	STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE				

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Europe, Middle East and Africa Technical Support:

Phone: 00421 33 790 2910

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